

4 Pre-Amend
T. Feaster
7/12/00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Mitsuru NISHITSUKA et al. Art Unit : Unknown
Serial No. : Unassigned Examiner : Unknown
Filed : March 1, 2000
Title : SEMICONDUCTOR LASER DEVICE PROVIDING LASER LIGHT OF TWO
WAVELENGTHS AND METHOD OF FABRICATING THE SAME

Assistant Commissioner for Patents
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Prior to examination, please amend the application as follows:

In the Claims:

Amend claims 4-8 and 10 as follows:

Claim 4, line 1, delete "or 3".

Claim 5, line 1, change "claims" to --claim--; and
line 2, delete "to 3".

Claim 6, line 1, change "claims" to --claim-- and delete "to" (second occurrence); and
line 2, delete "5".

7. (Amended) A method of fabricating a semiconductor laser device, the method comprising:

forming a laser assembly [**forming step composed of**] by:

[a step for] forming a multilayer structure body having at least an n-type semiconductor layer, an active layer and a p-type semiconductor layer deposited on a substrate,

[a step for] partly removing a top portion of the multilayer structure body so as to expose the n-type semiconductor layer, thus forming a ridge in a stripe fashion, and

[a step for] forming a first electrode on the top portion of the ridge and a second electrode on the lower portion of the ridge;